NSN 5961-01-107-2115

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-107-2115 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -45.0 reverse breakdown voltage, dc all transistor **Current Rating Per Characteristic:** 50.00 milliamperes forward current, dc all transistor **Power Rating Per Characteristic:** 400.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material: Terminal Type And Quantity:** 5 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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